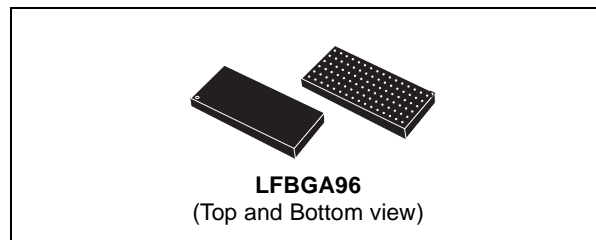# 74ALVCH32245

LOW VOLTAGE CMOS 32-BIT BUS TRANSCEIVER (3-STATE) WITH 3.6V TOLERANTAT INPUTS AND OUTPUTS

- 3.6V TOLERANT INPUTS AND OUTPUTS
- HIGH SPEED:
  t_{PD} = 3.0ns (MAX.) at V_{CC} = 3.0 to 3.6V
  t_{PD} = 3.7ns (MAX.) at V_{CC} = 2.3 to 2.7V
- POWER DOWN PROTECTION ON INPUTS AND OUTPUTS
- SYMMETRICAL OUTPUT IMPEDANCE:
  $|I_{OH}|$ = I_{OL} = 24mA (MIN) at V_{CC} = 3V
  $|I_{OH}|$ = I_{OL} = 8mA (MIN) at V_{CC} = 2.3V
- OPERATING VOLTAGE RANGE:
  V_{CC}(OPR) = 1.65V to 3.6V
- PIN AND FUNCTION COMPATIBLE WITH 74 SERIES 32245
- BUS HOLD PROVIDED ON BOTH SIDE
- LATCH-UP PERFORMANCE EXCEEDS 300mA
- ESD PERFORMANCE:
  HBM > 2000V (MIL STD 883 method 3015);
  MM > 200V

DESCRIPTION

The 74ALVCH32245 is a low voltage CMOS 32-BIT BUS TRANSCEIVER (3-STATE) fabricated with sub-micron silicon gate and five-layer metal wiring C^2MOS technology. It is ideal for 1.65 to 3.6 V applications; it can be interfaced to 3.6V signal environment for both inputs and outputs.

LFBGA96
(Top and Bottom view)

ORDER CODES

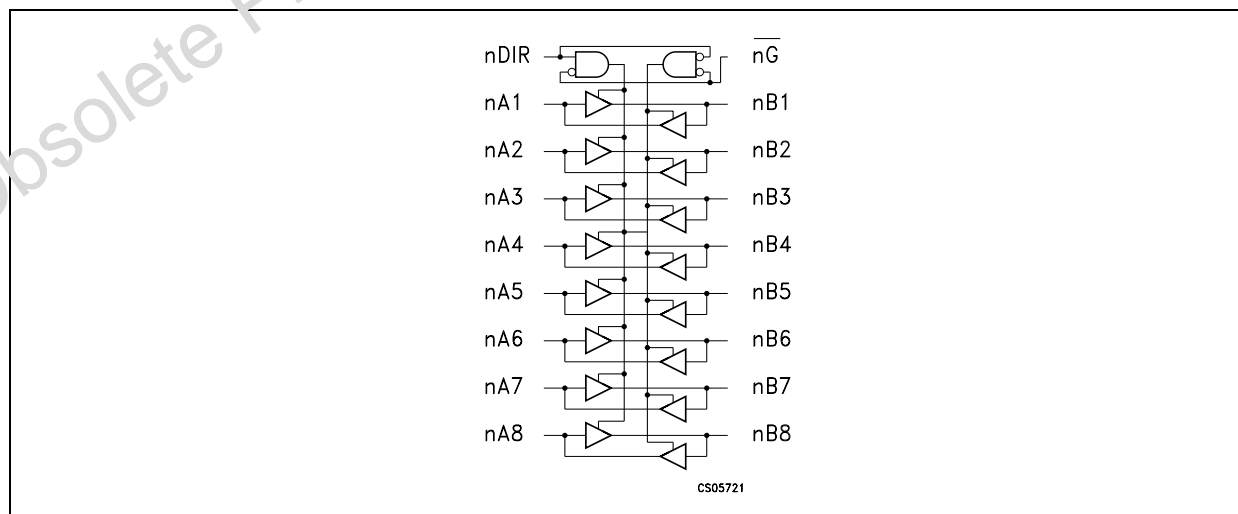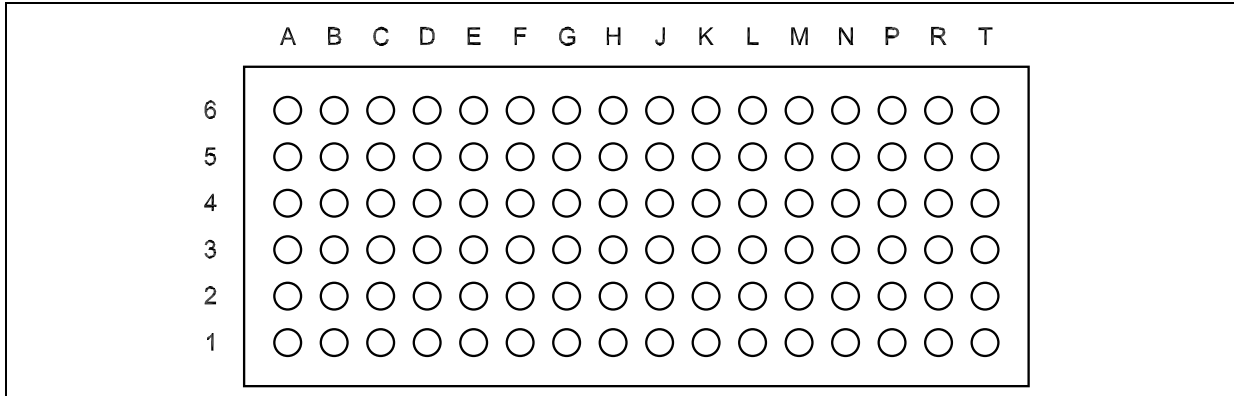| PACKAGE	TRAY	T & R
LFBGA96	74ALVCH32245LB	74ALVCH32245LBR

This IC is intended for two-ways asynchronous communication between data buses: the direction of data trasmission is determined by DIR input. Any nG control output governs eight BUS TRANSCEIVERS. Output Enable input (nG) tied together gives full 32-bit operation. When nG is LOW the output are enabled. When nG is HIGH, the output are in high impedance state so that the buses are effectively isolated. Bus hold on data inputs is provided in order to eliminate the need for external pull-up or pull-down resistor.

All inputs and outputs are equipped with protection circuits against static discharge, giving them 2KV ESD immunity and transient excess voltage.

LOGIC DIAGRAM

CS05721

PIN CONNECTION (Top view)

TERMINAL ASSIGNMENT

	A	B	C	D	E	F	G	H	J	K	L	M	N	P	R	T
6	1A2	1A4	1A6	1A8	2A2	2A4	2A6	2A7	3A2	3A4	3A6	3A8	4A2	4A4	4A6	4A7
5	1A1	1A3	1A5	1A7	2A1	2A3	2A5	2A8	3A1	3A3	3A5	3A7	4A1	4A3	4A5	4A8
4	$\overline{1G}$	GND	V_{CC}	GND	GND	V_{CC}	GND	$\overline{2G}$	$\overline{3G}$	GND	V_{CC}	GND	GND	V_{CC}	GND	$\overline{4G}$
3	1DIR	GND	V_{CC}	GND	GND	V_{CC}	GND	2DIR	3DIR	GND	V_{CC}	GND	GND	V_{CC}	GND	4DIR
2	1B1	1B3	1B5	1B7	2B1	2B3	2B5	2B8	3B1	3B3	3B5	3B7	4B1	4B3	4B5	4B8
1	1B2	1B4	1B6	1B8	2B2	2B4	2B6	2B7	3B2	3B4	3B6	3B8	4B2	4B4	4B6	4B7

INPUT AND OUTPUT EQUIVALENT CIRCUIT

SC08971
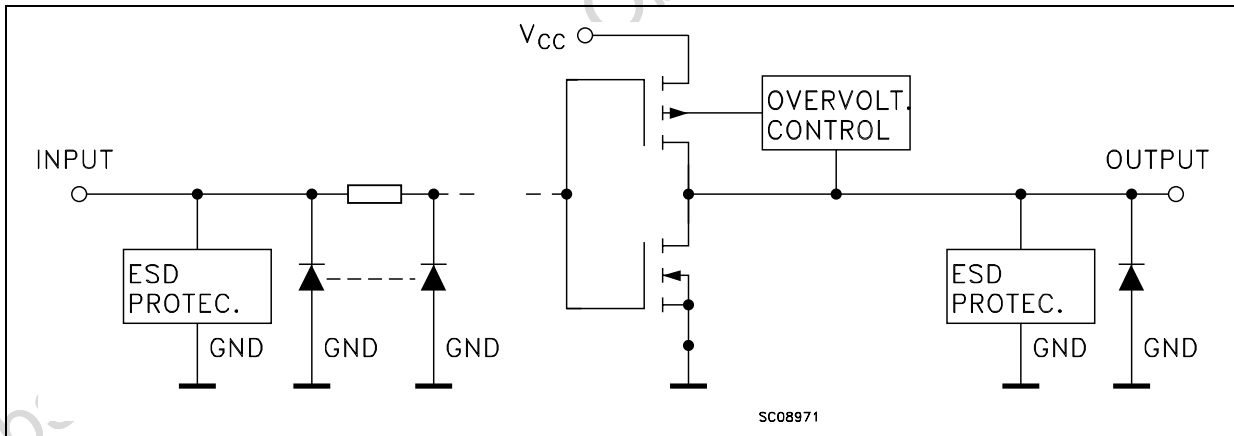
PIN DESCRIPTION

SYMBOL	NAME AND FUNCTION
nDIR	Directional Control
nA1 to nA8	Data Inputs/Outputs
nB1 to nB8	Data Inputs/Outputs
$n\overline{G}$	Output Enable Inputs
GND	Ground (0V)
V_{CC}	Positive Supply Voltage

TRUTH TABLE

INPUTS		FUNCTION		OUTPUT
$n\overline{G}$	nDIR	A BUS	B BUS	Yn
L	L	OUTPUT	INPUT	A = B
L	H	INPUT	OUTPUT	B = A
H	X	Z	Z	Z

X : Don't Care

Z : High Impedance

ABSOLUTE MAXIMUM RATINGS

Symbol	Parameter	Value	Unit
V_{CC}	Supply Voltage	-0.5 to +4.6	V
V_I	DC Input Voltage	-0.5 to +4.6	V
V_O	DC Output Voltage ($V_{CC} = 0V$)	-0.5 to +4.6	V
V_O	DC Output Voltage (High or Low State) (note 1)	-0.5 to V_{CC} + 0.5	V
I_{IK}	DC Input Diode Current	- 50	mA
I_{OK}	DC Output Diode Current (note 2)	- 50	mA
I_O	DC Output Current	$\pm$ 50	mA
I_{CC} or I_{GND}	DC V_{CC} or Ground Current per Supply Pin	$\pm$ 100	mA
P_D	Power Dissipation	400	mW
T_{stg}	Storage Temperature	-65 to +150	°C
T_L	Lead Temperature (10 sec)	300	°C

Absolute Maximum Ratings are those values beyond which damage to the device may occur. Functional operation under these conditions is not implied
1) I_O absolute maximum rating must be observed
2) V_O < GND

RECOMMENDED OPERATING CONDITIONS

Symbol	Parameter	Value	Unit
V_{CC}	Supply Voltage (note 1)	1.65 to 3.6	V
V_I	Input Voltage	0 to 3.6	V
V_O	Output Voltage ($V_{CC} = 0V$)	0 to 3.6	V
V_O	Output Voltage (High or Low State)	0 to V_{CC}	V
I_{OH}, I_{OL}	High or Low Level Output Current ($V_{CC} = 3.0$ to 3.6V)	$\pm$ 24	mA
I_{OH}, I_{OL}	High or Low Level Output Current ($V_{CC} = 2.7V$)	$\pm$ 12	mA
I_{OH}, I_{OL}	High or Low Level Output Current ($V_{CC} = 2.3$ to 2.5V)	$\pm$ 8	mA
T_{op}	Operating Temperature	-40 to +85	°C
dt/dv	Input Rise and Fall Time (note 2)	0 to 10	ns/V

1) Truth Table guaranteed: 1.2V to 3.6V
2) V_{IN} from 0.8V to 2V at $V_{CC} = 3.0V$

DC SPECIFICATIONS

Symbol	Parameter	Test Condition		Value		Unit
		V_{CC} (V)		-40 to 85 °C		
				Min.	Max.	
V_{IH}	High Level Input Voltage	1.65 to 1.95		$0.65V_{CC}$		V
		2.3 to 2.7		1.7		
		2.7 to 3.6		2.0		
V_{IL}	Low Level Input Voltage	1.65 to 1.95			$0.35V_{CC}$	V
		2.3 to 2.7			0.7	
		2.7 to 3.6			0.8	
V_{OH}	High Level Output Voltage	1.65 to 3.6	I_O=-100 µA	V_{CC}-0.2		V
		1.65	I_O=-4 mA	1.2		
		2.3	I_O=-8 mA	1.7		
		2.7	I_O=-12 mA	2.2		
		3.0	I_O=-12 mA	2.4		
		3.0	I_O=-24 mA	2.2		
V_{OL}	Low Level Output Voltage	1.65 to 3.6	I_O=100 µA		0.2	V
		1.65	I_O=4 mA		0.45	
		2.3	I_O=8 mA		0.7	
		2.7	I_O=12 mA		0.4	
		3.0	I_O=12 mA		0.4	
		3.0	I_O=24 mA		0.55	
I_I	Input Leakage Current	3.6	$V_I = V_{CC}$ or GND		± 5	µA
$I_{I(HOLD)}$	Input Hold Current	1.65	$V_I = 0.58V$	25		µA
		1.65	$V_I = 1.07V$	-25		
		2.3	$V_I = 0.7V$	45		
		2.3	$V_I = 1.7V$	-45		
		3	$V_I = 0.8V$	75		
		3	$V_I = 2V$	-75		
		3.6	$V_I = 0$ to $3.6V$		± 500	
I_{OZ}	High Impedance Output Leakage Current	3.6	$V_O = V_{CC}$ or GND		± 10	µA
I_{off}	Power Off Leakage Current	0	V_I or V_O = 0 to 3.6V		20	µA
I_{CC}	Quiescent Supply Current	3.6	$V_I = V_{CC}$ or GND, $I_O = 0$		40	µA
ΔI_{CC}	I_{CC} incr. per Input	3.0 to 3.6	$V_{IH} = V_{CC}$-0.6V other $V_I= V_{CC}$ or GND		750	µA

AC ELECTRICAL CHARACTERISTICS

Symbol	Parameter	Test Condition			Value		Unit
		V_{CC} (V)	C_L (pF)		-40 to 85 °C		
					Min.	Max.	
t_{PLH} t_{PHL}	Propagation Delay Time	2.3 to 2.7	30		1.0	3.7	ns
		2.7	50		1.0	3.6	
		3.0 to 3.6	50		1.0	3.0	
t_{PZL} t_{PZH}	Output Enable Time	2.3 to 2.7	30		1.0	5.7	ns
		2.7	50		1.0	5.4	
		3.0 to 3.6	50		1.0	4.4	
t_{PLZ} t_{PHZ}	Output Disable Time	2.3 to 2.7	30		1.0	5.2	ns
		2.7	50		1.0	4.6	
		3.0 to 3.6	50		1.0	4.1	

CAPACITIVE CHARACTERISTICS

Symbol	Parameter	Test Condition		Value			Unit
		V_{CC} (V)		T_A = 25 °C			
				Min.	Typ.	Max.	
C_{IN}	Input Capacitance	3.3	V_I = 0V or V_{CC}		4		pF
C_{OUT}	Output Capacitance	3.3	V_I = 0V or V_{CC}		8		pF
C_{PD}	Power Dissipation Capacitance (note 1)	2.5	f_{IN} = 10MHz		22		pF
		3.3	V_I = 0V or V_{CC}		28		

1) C_{PD} is defined as the value of the IC's internal equivalent capacitance which is calculated from the operating current consumption without load. (Refer to Test Circuit). Average operating current can be obtained by the following equation. $I_{CC(opr)} = C_{PD} \times V_{CC} \times f_{IN} + I_{CC}/32$ (per circuit)

TEST CIRCUIT

SC11690
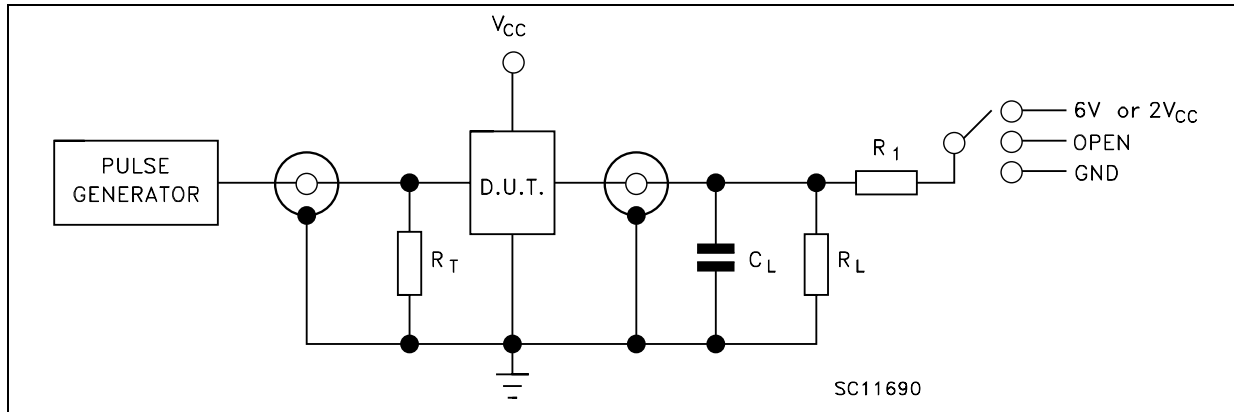
TEST	SWITCH
t_{PLH}, t_{PHL}	Open
t_{PZL}, t_{PLZ} (V_{CC} = 3.0 to 3.6V)	6V
t_{PZL}, t_{PLZ} (V_{CC} = 2.3 to 2.7V)	$2V_{CC}$
t_{PZH}, t_{PHZ}	GND

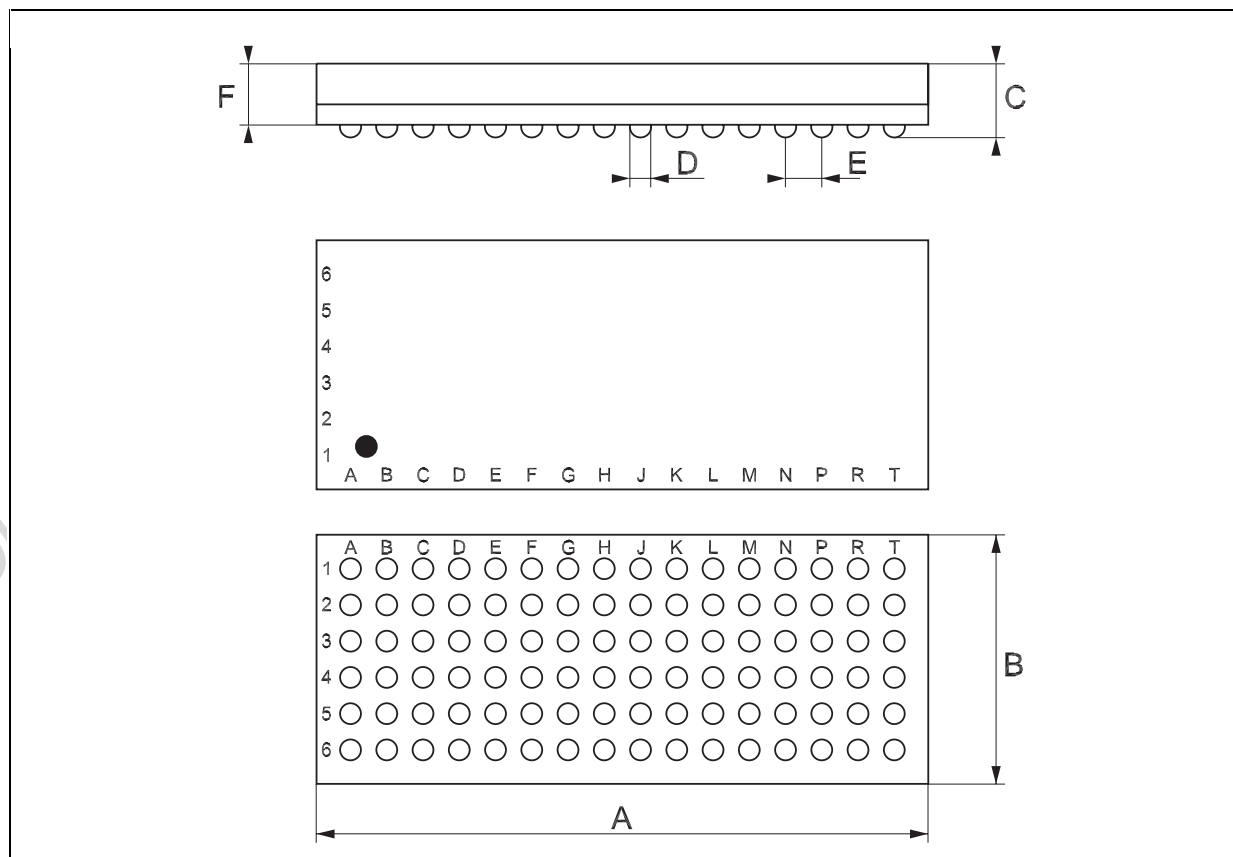R_T = Z_{OUT} of pulse generator (typically 50Ω)

TEST CIRCUIT AND WAVEFORM SYMBOL VALUE

Symbol	V_{CC}			
	3.0 to 3.6V	2.7V	2.3 to 2.7V	1.65 to 1.95V
V_{IH}	2.7V	2.7V	V_{CC}	V_{CC}
V_M	1.5V	1.5V	$V_{CC}/2$	$V_{CC}/2$
V_X	V_{OL} +0.3V	V_{OL} +0.3V	V_{OL} +0.15V	V_{OL} +0.15V
V_Y	V_{OH} -0.3V	V_{OH} -0.3V	V_{OH} -0.15V	V_{OH} -0.15V
C_L	50pF	50pF	30pF	30pF
$R_L=R_1$	500Ω	500Ω	500Ω	1000Ω
$t_r = t_r$	<2.5ns	<2.5ns	<2.0ns	<2.0ns

WAVEFORM 1: PROPAGATION DELAY (f=1MHz; 50% duty cycle)

CS07310
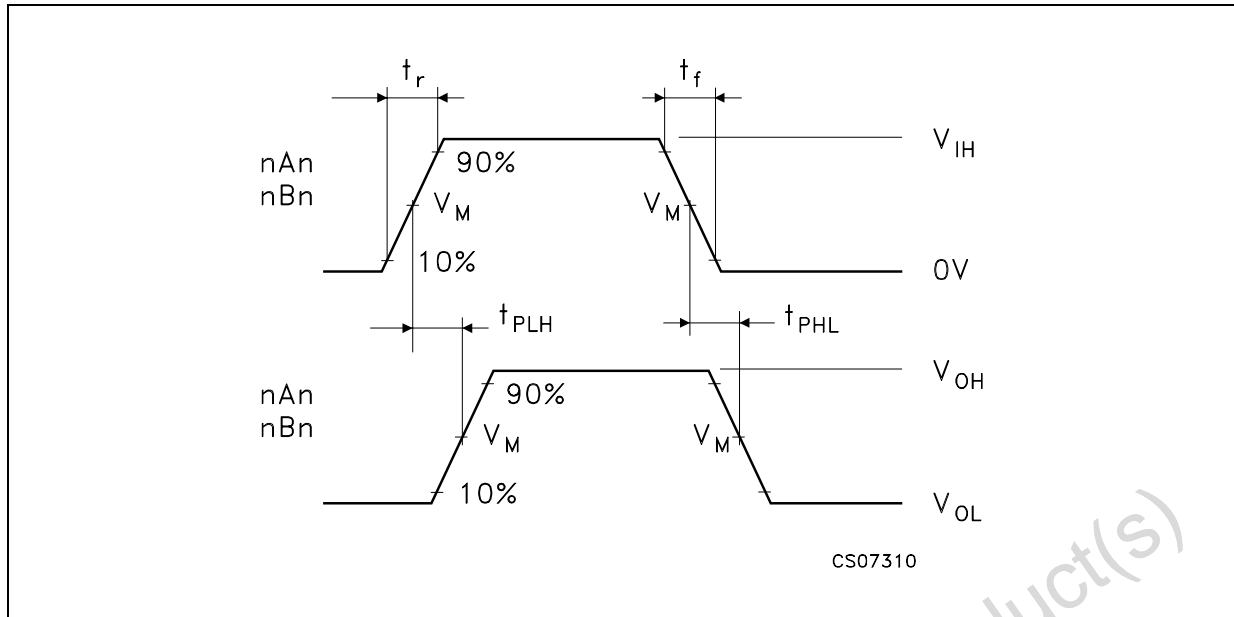
WAVEFORM 2: OUTPUT ENABLE AND DISABLE TIME (f=1MHz; 50% duty cycle)

CS07320
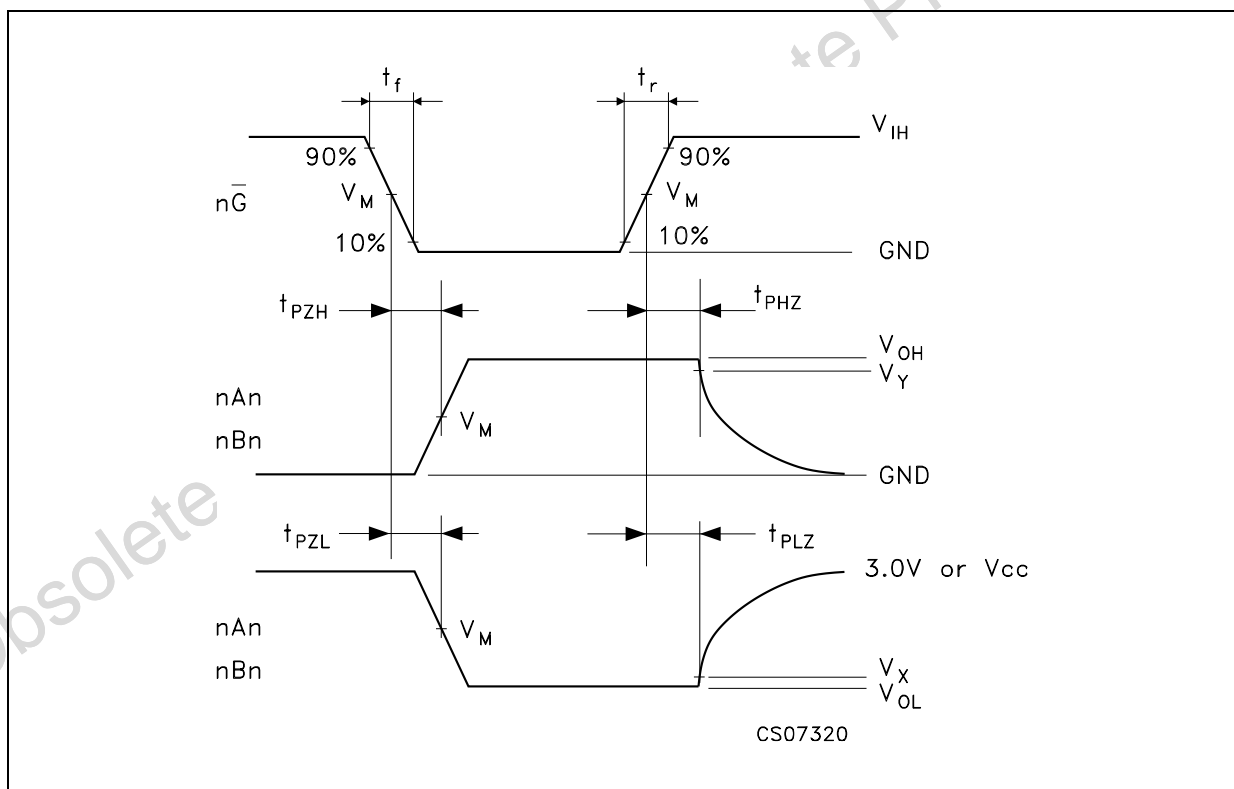
LFBGA96 MECHANICAL DATA

DIM.	mm.			mils		
	MIN.	TYP	MAX.	MIN.	TYP.	MAX.
A	13.40		13.60	527.5		535.4
B	5.40		5.60	212.6		220.5
C			1.6			63.0
D		0.5			19.7	
E		0.8			31.5	
F	1		.15			45.3